

# 1 Characteristics

**Table 1. Absolute Ratings (limiting values)**

| Symbol              | Parameter   |                               |   |                         | Value        | Unit |
|---------------------|---|-------------------------------|---|-------------------------|--------------|------|
| V <sub>RRM</sub>    | Repetitive peak reverse voltage                       |                               |   |                         | 45           | V    |
| I <sub>F(RMS)</sub> | RMS forward voltage                                   |                               |   |                         | 30           | A    |
| I <sub>F(AV)</sub>  | Average forward current                               | TO-220AB / D <sup>2</sup> PAK | T <sub>c</sub> = 135° C<br>δ = 0.5          | Per diode<br>Per device | 10<br>20     | A    |
|                     |   | TO-220FPAB                    | T <sub>c</sub> = 115° C<br>δ = 0.5          | Per diode<br>Per device | 10<br>20     | A    |
| I <sub>FSM</sub>    | Surge non repetitive forward current                  |                               | t <sub>p</sub> = 10 ms Sinusoidal           |                         | 180          | A    |
| I <sub>RRM</sub>    | Peak repetitive reverse current                       |                               | t <sub>p</sub> = 2 μs square F = 1 kHz      |                         | 1            | A    |
| I <sub>RSM</sub>    | Non repetitive peak reverse current                   |                               | t <sub>p</sub> = 100 μs square              |                         | 2            | A    |
| P <sub>ARM</sub>    | Repetitive peak avalanche power                       |                               | t <sub>p</sub> = 1 μs T <sub>j</sub> = 25°C |                         | 4000         | W    |
| T <sub>stg</sub>    | Storage temperature range                             |                               |   |                         | -65 to + 150 | °C   |
| T <sub>j</sub>      | Maximum operating junction temperature <sup>(1)</sup> |                               |   |                         | 150          | °C   |
| dV/dt               | Critical rate of rise of reverse voltage              |                               |   |                         | 10000        | V/μs |

1.  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  condition to avoid thermal runaway for a diode on its own heatsink

**Table 2. Thermal resistances**

| Symbol        | Parameter        |                               |           | Value | Unit                |
|---------------|------------------|-------------------------------|-----------|-------|---------------------|
| $R_{th(j-c)}$ | Junction to case | TO-220FPAB                    | Per diode | 4.5   | $^\circ \text{C/W}$ |
|               |                  |                               | Total     | 3.5   |                     |
|               |                  |                               | Coupling  | 2.5   |                     |
| $R_{th(j-c)}$ | Junction to case | TO-220AB / D <sup>2</sup> PAK | Per diode | 2.2   | $^\circ \text{C/W}$ |
|               |                  |                               | Total     | 1.3   |                     |
|               |                  |                               | Coupling  | 0.3   |                     |

When the diodes 1 and 2 are used simultaneously :

$$\Delta T_j(\text{diode } 1) = P(\text{diode } 1) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode } 2) \times R_{th(c)}.$$

**Table 3. Static electrical characteristics (per diode)**

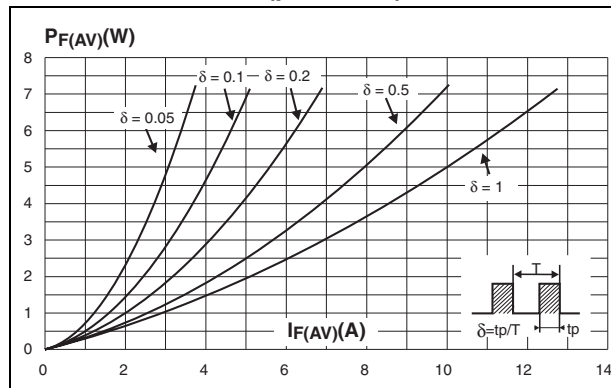
| Symbol      | Parameter               | Test Conditions            |                      | Min. | Typ. | Max. | Unit |
|-------------|-------------------------|----------------------------|----------------------|------|------|------|------|
| $I_R^{(1)}$ | Reverse leakage current | $T_j = 25^\circ \text{C}$  | $V_R = V_{RRM}$      |      |      | 0.2  | mA   |
|             |                         | $T_j = 125^\circ \text{C}$ |                      |      | 65   | 130  | mA   |
| $V_F^{(1)}$ | Forward voltage drop    | $T_j = 25^\circ \text{C}$  | $I_F = 10 \text{ A}$ |      |      | 0.55 | V    |
|             |                         | $T_j = 125^\circ \text{C}$ | $I_F = 10 \text{ A}$ |      | 0.44 | 0.5  |      |
|             |                         | $T_j = 25^\circ \text{C}$  | $I_F = 20 \text{ A}$ |      |      | 0.73 |      |
|             |                         | $T_j = 125^\circ \text{C}$ | $I_F = 20 \text{ A}$ |      | 0.62 | 0.72 |      |

1. Pulse test:  $t_p = 380 \mu\text{s}$ ,  $\delta < 2\%$

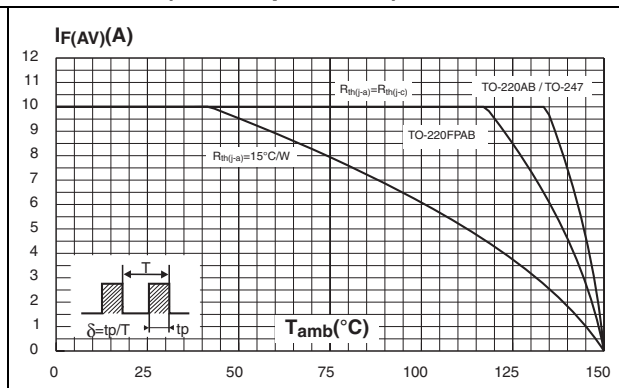
To evaluate the conduction losses use the following equation:

$$P = 0.28 \times I_{F(AV)} + 0.022 I_{F(RMS)}^2$$

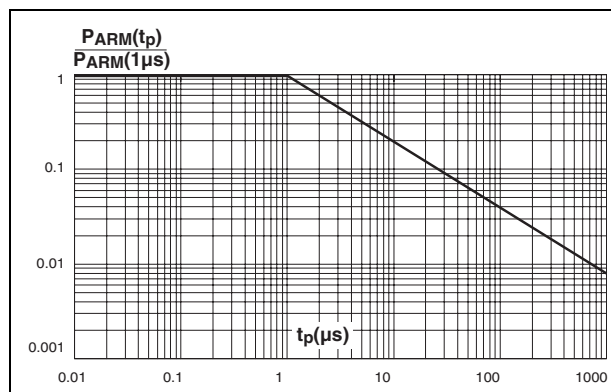
**Figure 1. Average forward power dissipation versus average forward current (per diode)**



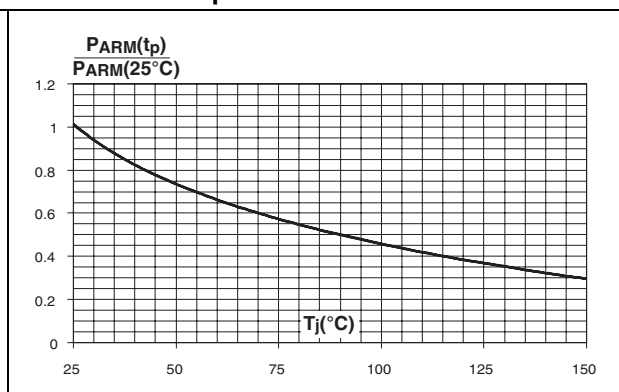
**Figure 2. Average forward current versus ambient temperature ( $\delta = 0.5$ , per diode)**



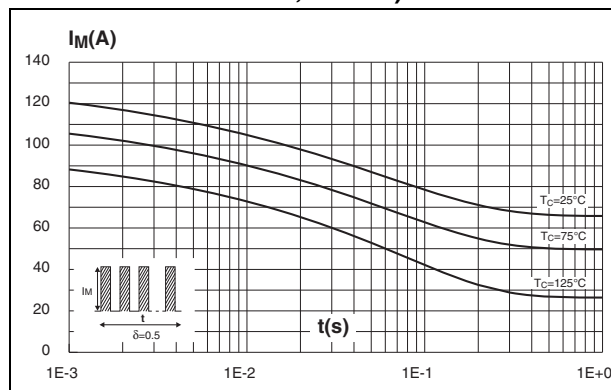
**Figure 3. Normalized avalanche power derating versus pulse duration**



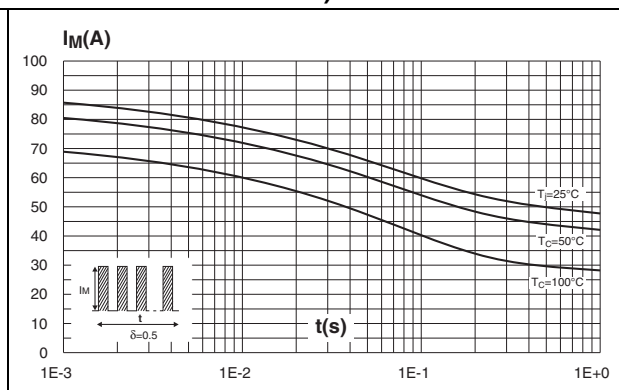
**Figure 4. Normalized avalanche power derating versus junction temperature**



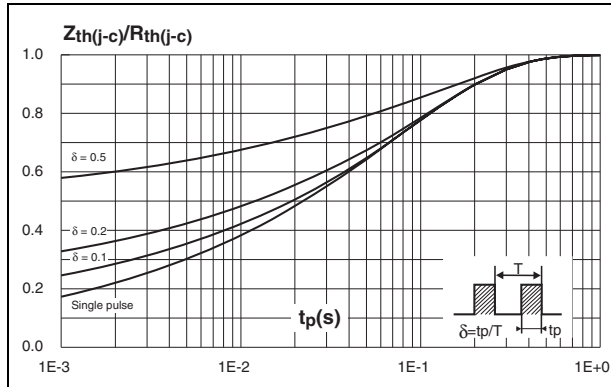
**Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode, TO-220AB, D<sup>2</sup>PAK)**



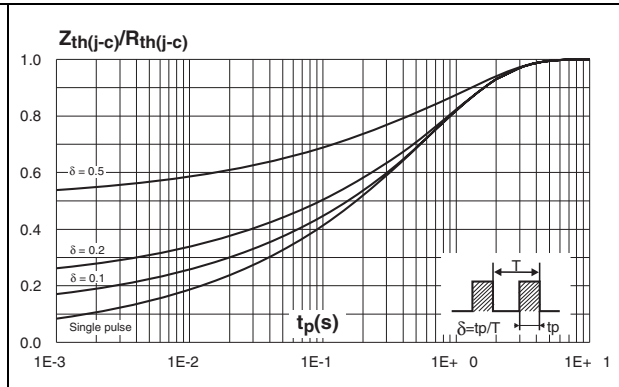
**Figure 6. Non repetitive surge peak forward current versus overload duration (maximum values, per diode, TO-220FPAB)**



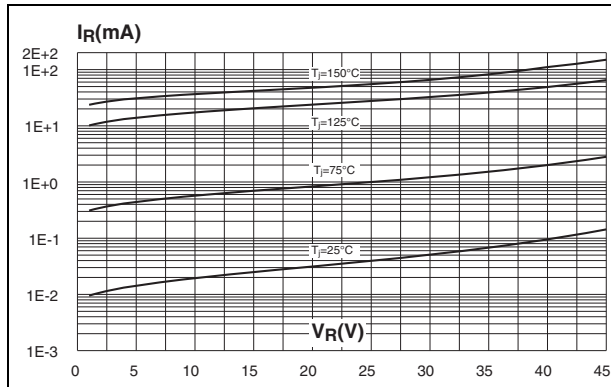
**Figure 7. Relative variation of thermal impedance junction to case versus pulse duration (TO-220AB, D<sup>2</sup>PAK)**



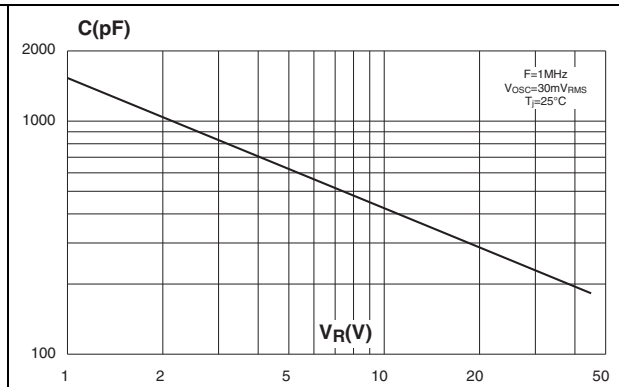
**Figure 8. Relative variation of thermal impedance junction to case versus pulse duration (TO-220FPAB)**



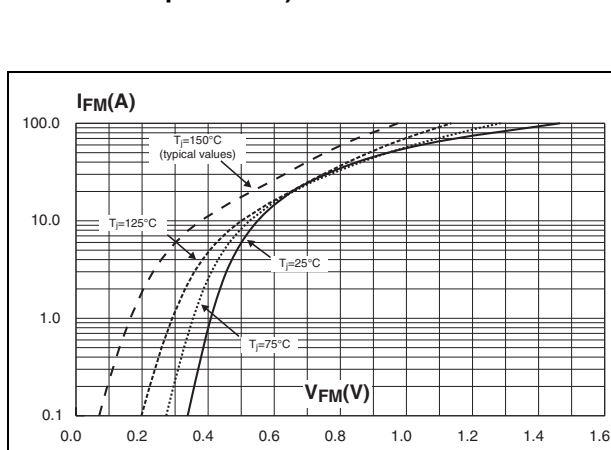
**Figure 9. Reverse leakage current versus reverse voltage applied (typical values, per diode)**



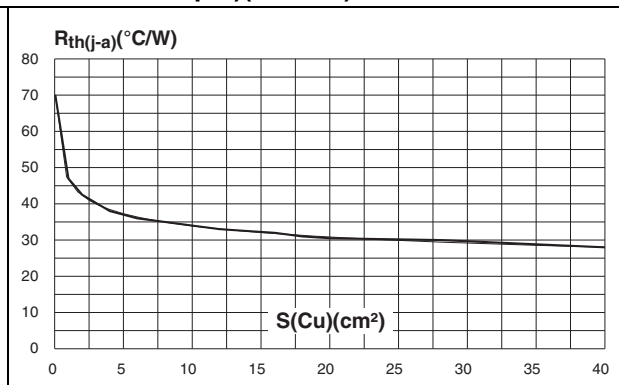
**Figure 10. Junction capacitance versus reverse voltage applied (typical values, per diode)**



**Figure 11. Forward voltage drop versus forward current (maximum values, per diode)**



**Figure 12. Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness: 35μm)( D<sup>2</sup>PAK)**



## 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.55 Nm
- Maximum torque value: 0.70 Nm

Table 4. TO-220FPAB dimensions

| Ref  | Dimensions  |      |           |       |
|------|-------------|------|-----------|-------|
|      | Millimeters |      | Inches    |       |
|      | Min.        | Max. | Min.      | Max.  |
| A    | 4.4         | 4.6  | 0.173     | 0.181 |
| B    | 2.5         | 2.7  | 0.098     | 0.106 |
| D    | 2.5         | 2.75 | 0.098     | 0.108 |
| E    | 0.45        | 0.70 | 0.018     | 0.027 |
| F    | 0.75        | 1    | 0.030     | 0.039 |
| F1   | 1.15        | 1.70 | 0.045     | 0.067 |
| F2   | 1.15        | 1.70 | 0.045     | 0.067 |
| G    | 4.95        | 5.20 | 0.195     | 0.205 |
| G1   | 2.4         | 2.7  | 0.094     | 0.106 |
| H    | 10          | 10.4 | 0.393     | 0.409 |
| L2   | 16 Typ.     |      | 0.63 Typ. |       |
| L3   | 28.6        | 30.6 | 1.126     | 1.205 |
| L4   | 9.8         | 10.6 | 0.386     | 0.417 |
| L5   | 2.9         | 3.6  | 0.114     | 0.142 |
| L6   | 15.9        | 16.4 | 0.626     | 0.646 |
| L7   | 9.00        | 9.30 | 0.354     | 0.366 |
| Dia. | 3.00        | 3.20 | 0.118     | 0.126 |

Table 5. TO-220AB dimensions

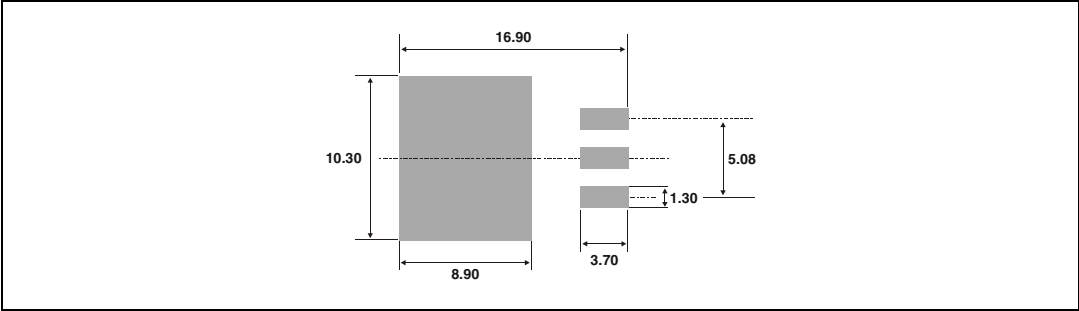
| Ref   | Dimensions  |       |            |       |
|-------|-------------|-------|------------|-------|
|       | Millimeters |       | Inches     |       |
|       | Min.        | Max.  | Min.       | Max.  |
| A     | 4.40        | 4.60  | 0.173      | 0.181 |
| C     | 1.23        | 1.32  | 0.048      | 0.051 |
| D     | 2.40        | 2.72  | 0.094      | 0.107 |
| E     | 0.49        | 0.70  | 0.019      | 0.027 |
| F     | 0.61        | 0.88  | 0.024      | 0.034 |
| F1    | 1.14        | 1.70  | 0.044      | 0.066 |
| F2    | 1.14        | 1.70  | 0.044      | 0.066 |
| G     | 4.95        | 5.15  | 0.194      | 0.202 |
| G1    | 2.40        | 2.70  | 0.094      | 0.106 |
| H2    | 10          | 10.40 | 0.393      | 0.409 |
| L2    | 16.4 typ.   |       | 0.645 typ. |       |
| L4    | 13          | 14    | 0.511      | 0.551 |
| L5    | 2.65        | 2.95  | 0.104      | 0.116 |
| L6    | 15.25       | 15.75 | 0.600      | 0.620 |
| L7    | 6.20        | 6.60  | 0.244      | 0.259 |
| L9    | 3.50        | 3.93  | 0.137      | 0.154 |
| M     | 2.6 typ.    |       | 0.102 typ. |       |
| Diam. | 3.75        | 3.85  | 0.147      | 0.151 |

The technical drawing shows two views of a TO-220AB package. The top view (left) shows a rectangular body with a central circular feature. Dimensions labeled include H2 (width of the top flange), Dia (diameter of the central feature), L5 (height of the top flange), L6 (height of the main body), L9 (height of the mounting tab), L4 (height of the base), F2 (width of the mounting tab), F1 (width of the base), F (width of the base), G1 (width of the base), and G (width of the base). The side view (right) shows the profile of the package. Dimensions labeled include A (total height), C (height of the top flange), L7 (height of the main body), D (width of the mounting tab), M (width of the base), and E (width of the base).

Table 6. D<sup>2</sup>PAK dimensions

| Ref | Dimensions  |       |            |       |
|-----|-------------|-------|------------|-------|
|     | Millimeters |       | Inches     |       |
|     | Min.        | Max.  | Min.       | Max.  |
| A   | 4.40        | 4.60  | 0.173      | 0.181 |
| A1  | 2.49        | 2.69  | 0.098      | 0.106 |
| A2  | 0.03        | 0.23  | 0.001      | 0.009 |
| B   | 0.70        | 0.93  | 0.027      | 0.037 |
| B2  | 1.14        | 1.70  | 0.045      | 0.067 |
| C   | 0.45        | 0.60  | 0.017      | 0.024 |
| C2  | 1.23        | 1.36  | 0.048      | 0.054 |
| D   | 8.95        | 9.35  | 0.352      | 0.368 |
| E   | 10.00       | 10.40 | 0.393      | 0.409 |
| G   | 4.88        | 5.28  | 0.192      | 0.208 |
| L   | 15.00       | 15.85 | 0.590      | 0.624 |
| L2  | 1.27        | 1.40  | 0.050      | 0.055 |
| L3  | 1.40        | 1.75  | 0.055      | 0.069 |
| M   | 2.40        | 3.20  | 0.094      | 0.126 |
| R   | 0.40 typ.   |       | 0.016 typ. |       |
| V2  | 0°          | 8°    | 0°         | 8°    |

Figure 13. Footprint (dimensions in millimeters)



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com).

### 3 Ordering Information

| Ordering type  | Marking      | Package            | Weight | Base qty | Delivery mode |
|----------------|--------------|--------------------|--------|----------|---------------|
| STPS20L45CFP   | STPS20L45CFP | TO-220FPAB         | 2 g    | 50       | Tube          |
| STPS20L45CT    | STPS20L45CT  | TO-220AB           | 2 g    | 50       | Tube          |
| STPS20L45CG    | STPS20L45CG  | D <sup>2</sup> PAK | 1.48 g | 50       | Tube          |
| STPS20L45CG-TR | STPS20L45CG  | D <sup>2</sup> PAK | 1.48 g | 1000     | Tape & Reel   |

### 4 Revision history

| Date        | Revision | Description of Changes               |
|-------------|----------|--------------------------------------|
| Jul_2003    | 3C       | Last release.                        |
| 22-Mar-2007 | 4        | Removed ISOWATT and TO-247 packages. |

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